

36.07

()	12.16
A ()	2.37
()	438.58
()	50.99/35.66
300	3625
	2722

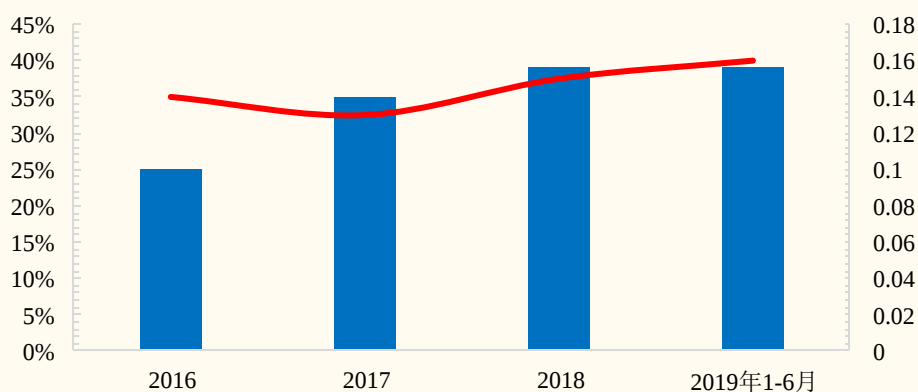
SAC S1130520010001
zhengbiyu gjzq.com.cn

SAC S1130519100004
zhang_chun gjzq.com.cn

SAC

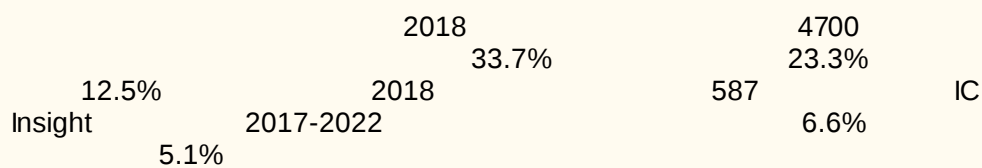
18	2016-2021	12
19		12
20		13
21		13
22	MOSFET IGBT BJT	13
23		13
24		14
25	GaN SiC	15
26		15
27		16
28	2018 IGBTs	16
29	2018 MOSFET	16
30		17
31	2020 2 18	18
32		18
33		19
34		19
35		19
36	IC	20
37		20
38		21
39		21
40	2018	22
41	2018	22
42		22
43		24
44		25
45		25
46	2020.03.23 ,	25
47		26

5

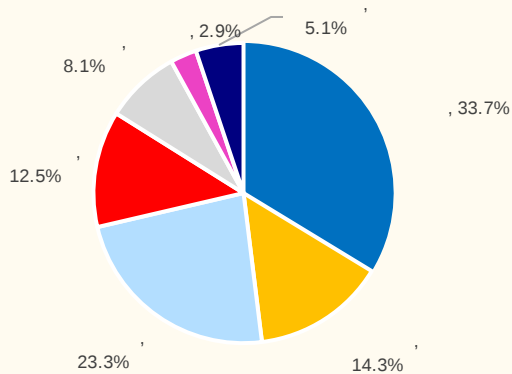


3.

IC



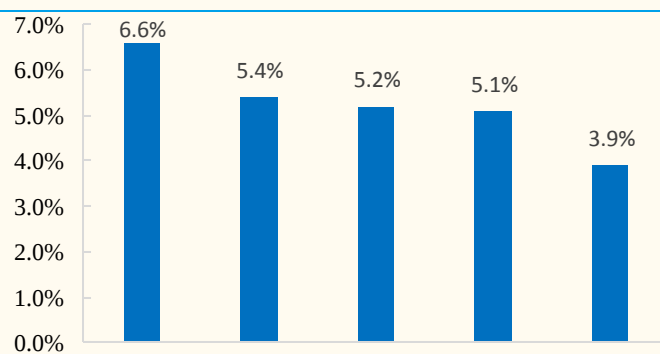
6 2018



WSTS

7

2017-2022E



IC Insight

120 /

68 /

MEMS SOI BCD/CDMOS MEMS 130nm 5nm 3nm EUV ; RF-COMS SOI/RF-IC

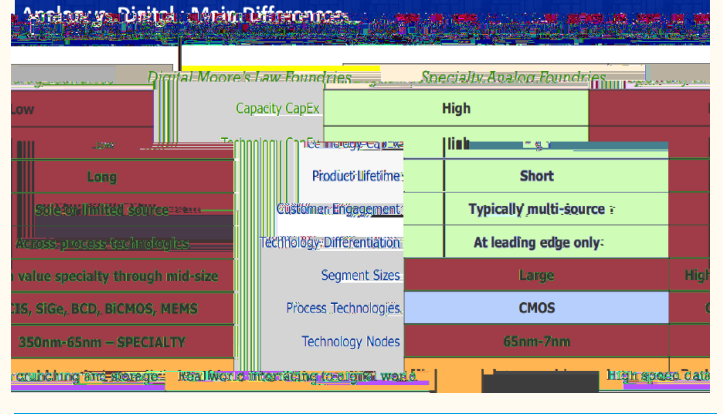
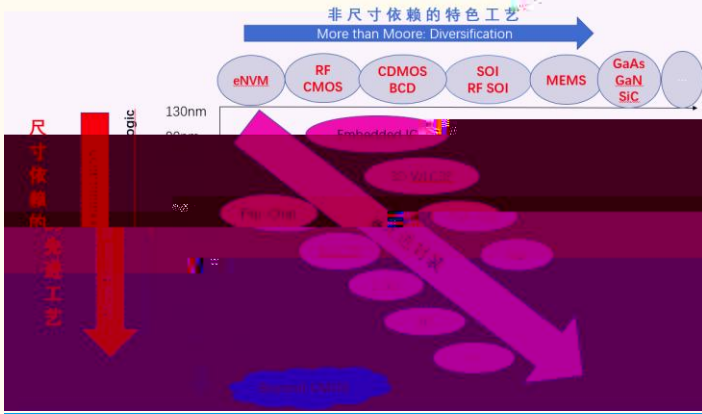
2018

238
119
400 /
2019
90%
58
35%
8
1450 /
37 /
68 /
75
38 /
120 /
77
ASP

8

9

vs.



8

12

12

8

8

RF-COMS SOI/RF-SOI BCD/CDMOS

8

Hynix

8

8

8

IC

IC

MOSFET
MCU IGBT MOSFET

CIS

8

92.5%

MOSFET

MOSFET

10

MOSFET

技术	制造商	目前货期	货期趋势	目前价格
低压 Mosfet	Infinion	15-30	延长	稳定
	Diodes Inc.	21-25	延长	稳定
	ON Semiconductor (Fairchild)	15-24	延长	稳定
	ON Semiconductor	13-20	延长	稳定
	Nexperia	12-20	延长	稳定
	STMicroelectronics	17-30	延长	稳定
	Vishay	17-22	延长	稳定
高压 Mosfet	Infinion	21-26	延长	稳定
	ON Semiconductor (Fairchild)	15-22	延长	依据市场进行选择性调整
	IXYS	22-30	延长	稳定
	STMicroelectronics	19-24	延长	依据市场进行选择性调整
	ROHM	18-22	延长	稳定
	Microsemi	25-30	延长	稳定
	Vishay	15-17	延长	依据市场进行选择性调整

4.

2016 2018
44,976 34,559 44,742
7.86% 7.61% 7.17%

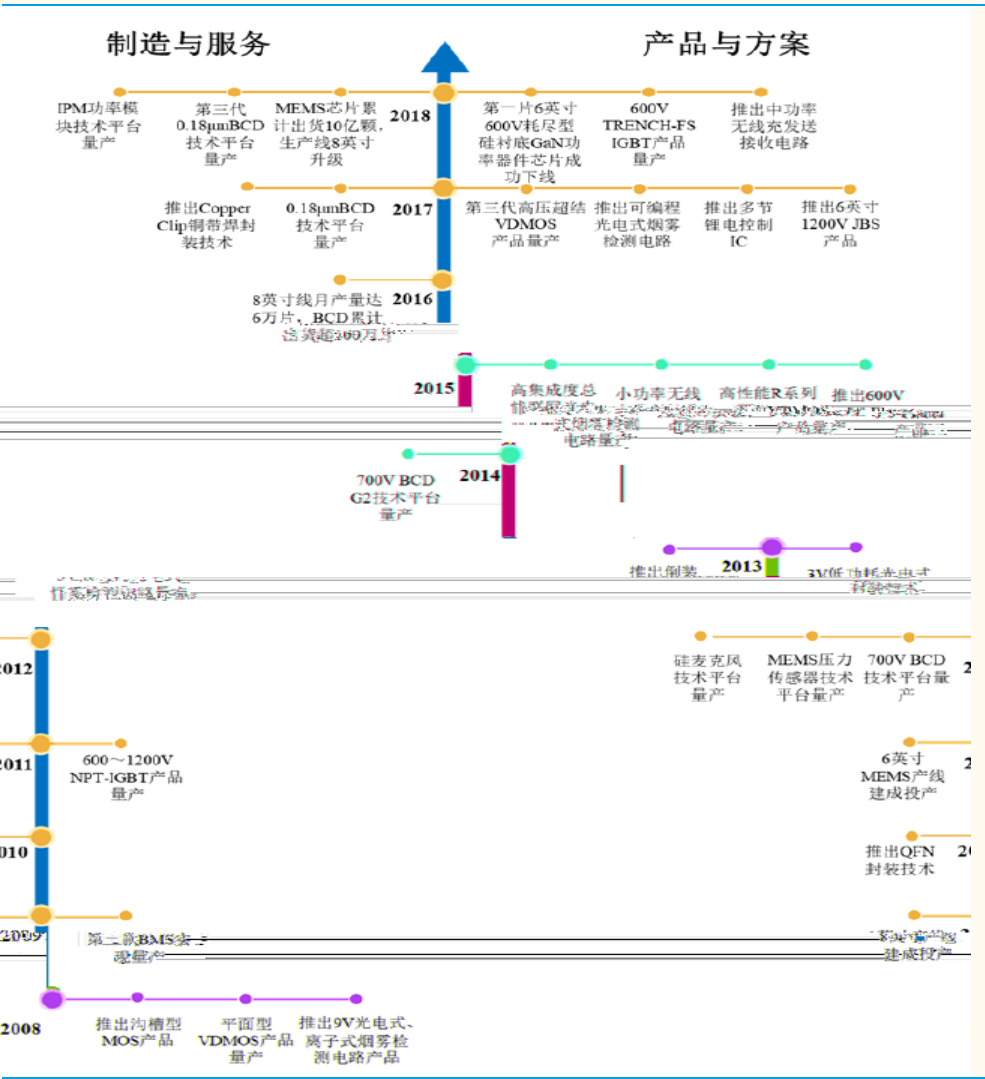
2019 6 30 7937 641 2290
37%

11			

EDA

MOSFET IGBT BMS GaN
BCD MEMS

12 2008

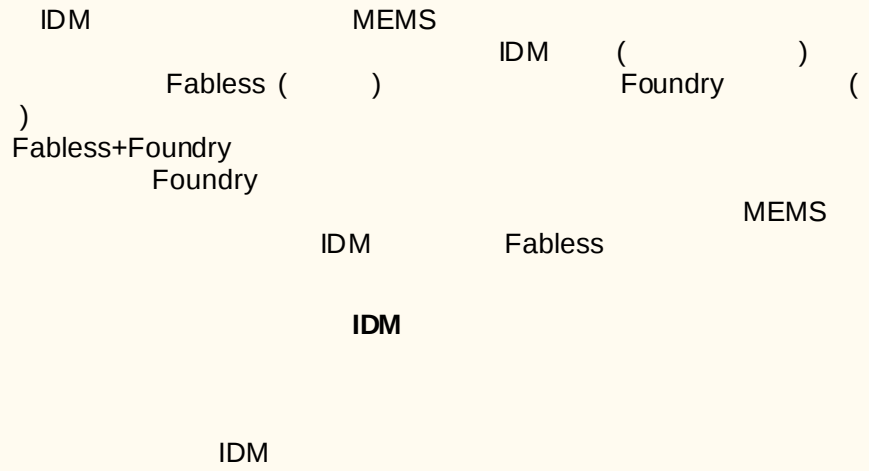


MOSFET IGBT FRD MEMS
 SBD
 BCD

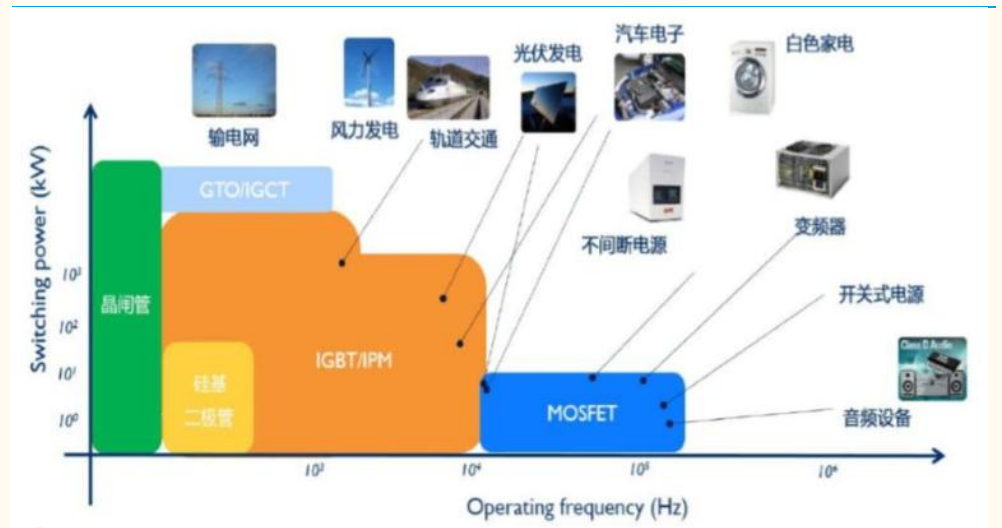
13

BCD	1 2 3	1.0-0.18μm	5V 700V 200 600V SOI	BCD	BCD SOI BCD
MEMS	1 2 3	MEMS	MEMS	MEMS	
	220	TO-3P TO247	IPM DPAK PDFN IPM	TO-	MOSFET IPM

1. IDM

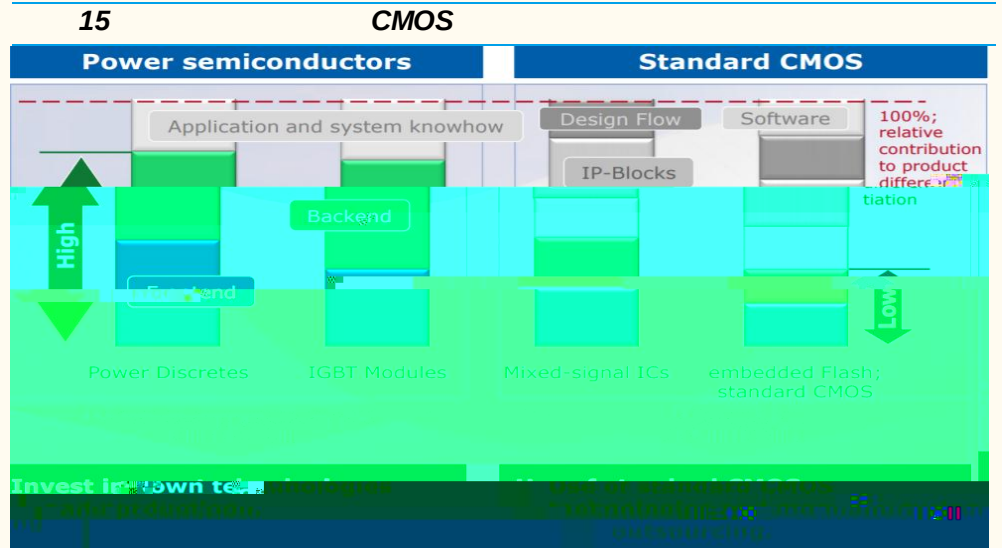


14



Yole

IP



IDM

IP
MOSFET
700V BCD G2
IPM

Fabless

IDM

VDMOS
600V TRENCH FS IGBT

IDM
IDM

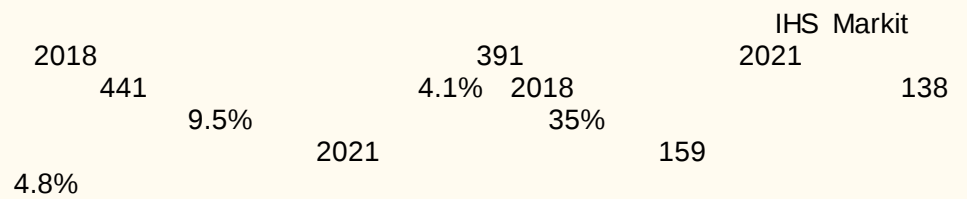
2008
NPT-IGBT
VDMOS

700V BCD
1200V JBS

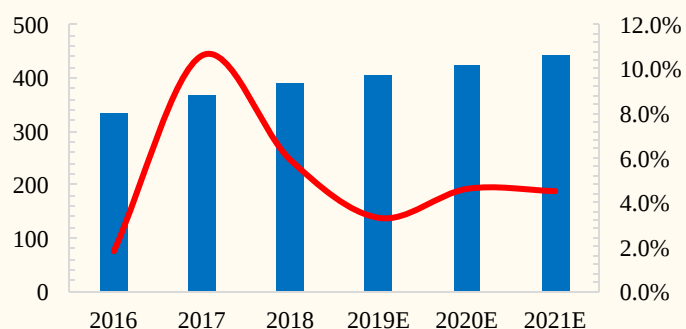
16

		IDM
		IDM
	IC	IC
	MOSFET	IGBT
		IDM
		IDM
	MOSFET	
	(NXP)	
	MOSFET IGBT	IC SiC
		IDM

2.

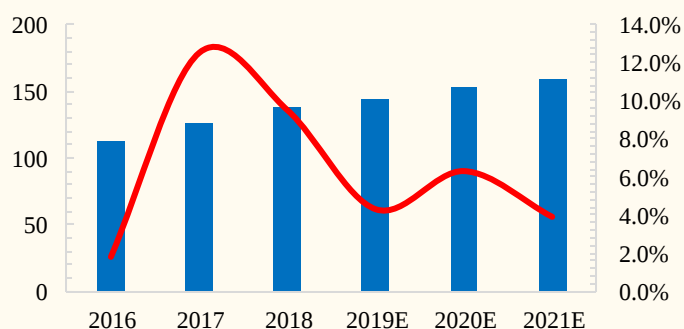


17 2016-2021



IHS Markit

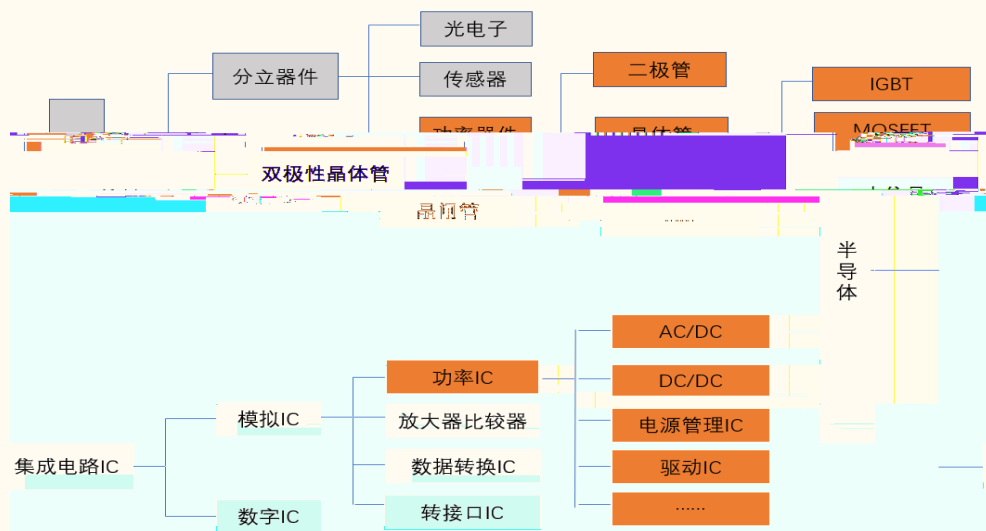
18 2016-2021



IHS Markit

IC
IGBT/MOSFET/BJT
Yole Development
2018
/ / IC 32.7% 13.3% 54.0%

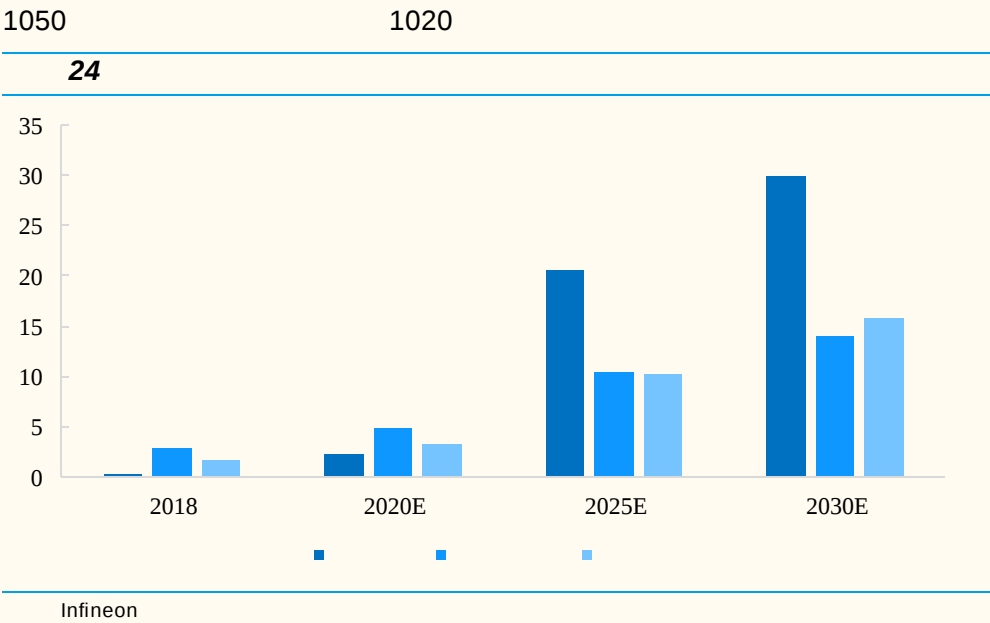
19



	MOSFET	IGBT	SiC	
	20%	20%	18%	23%
MOSFET	IGBT			15%
MOSFET		41%	21%	23%
IGBT	7%			

20

21



300 1050

2000 Infineon 100 kW IEA 2030 200-

2019 1900 47.5

CAGR 5.9%

CAGR 8.8%

30

2015-2025 15-25 CAGR 16.4%

1MW

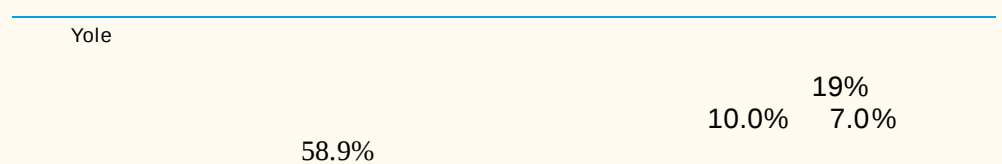
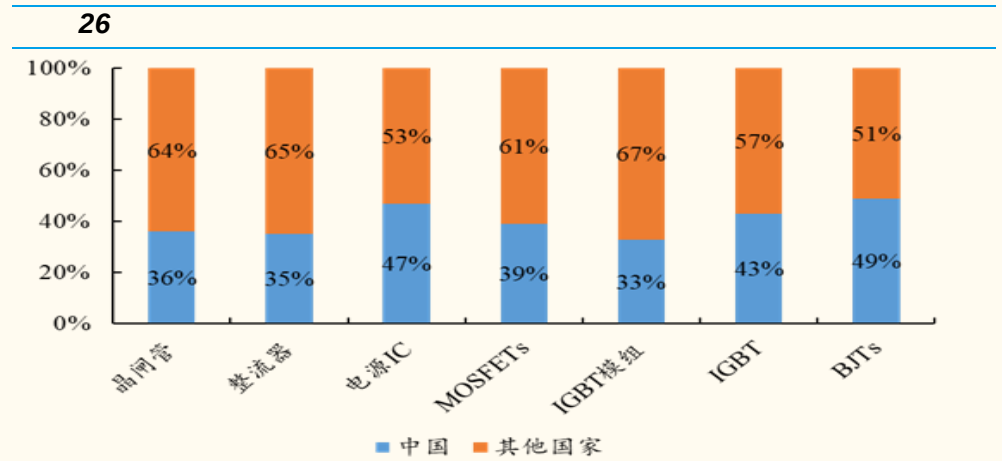
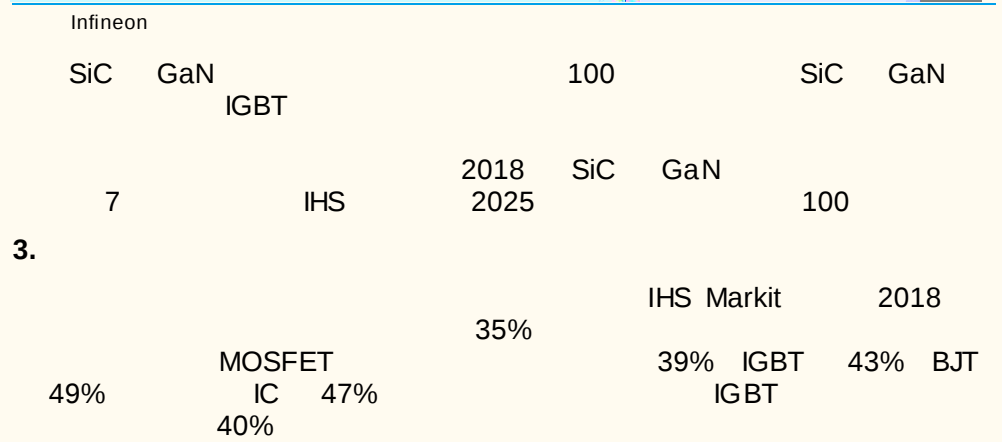
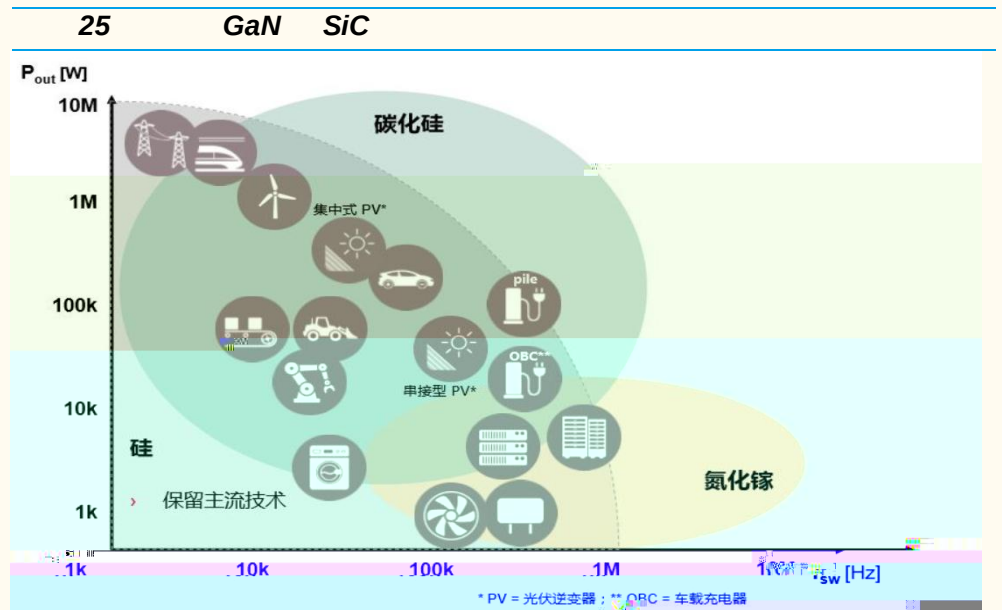
IGBT

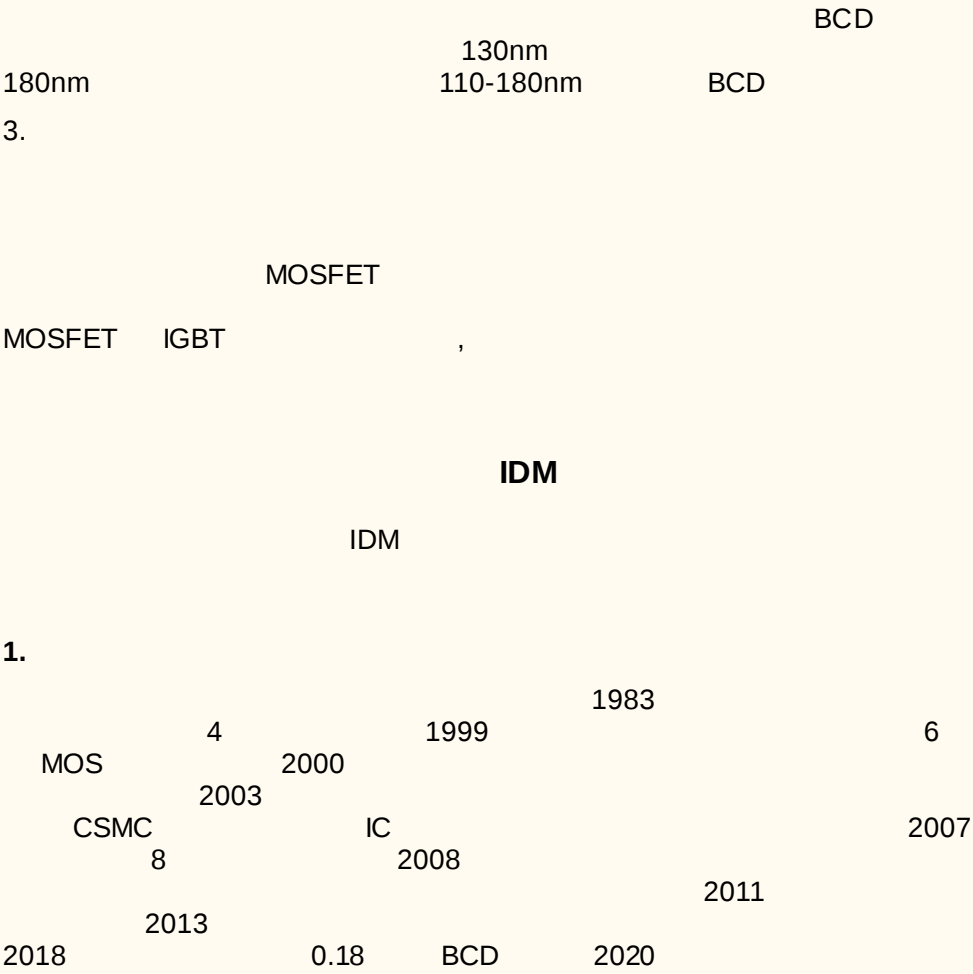
SiC GaN

SiC GaN

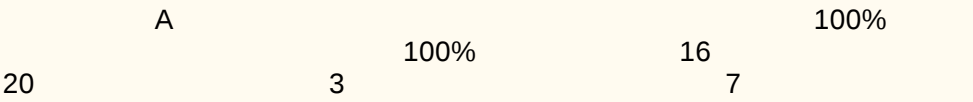
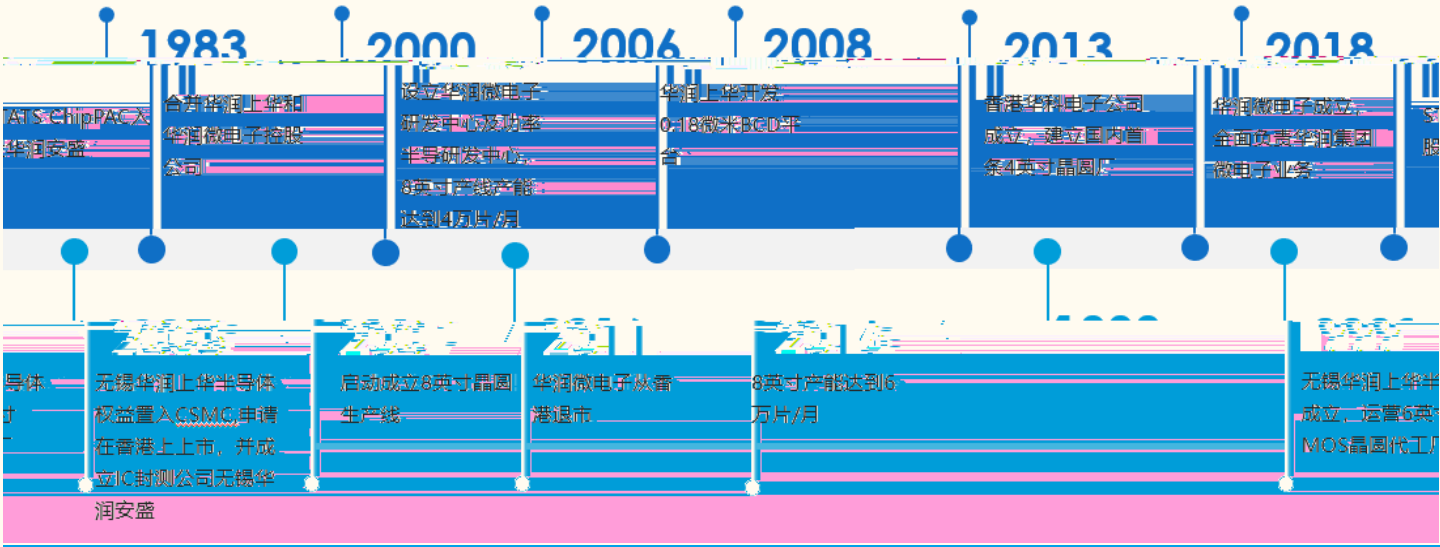
SiC (>600V) GaN

SiC GaN





30



31

2020 2 18

2. IDM+

43% 2016 31% 2019

32

	2019 1-6		2018		2017		2016	
	1140	43%	2683	43%	2339	40%	1332	31%
	1028	39%	2419	39%	2069	35%	1081	25%
	62	2%	138	2%	97	2%	85	2%

AC-DC
LED IC BMS IC
LED IC
IC
WPC QI IC IC BCD
CMOS

36 IC		
AC-DC	AC-DC	
LED IC	LED	
BMS IC		
IC	78 1117 100mA-1A	
IC	100W	
IC		
IC	AB D 5mW-50W	

MEMS MEMS

37		
MEMS		

4 8 16 32 CPU MCU MCU MCU

38

MCU	MCU PC MCU	
MCU	MCU MCU	
MCU	CPU 8 16 32	

2)

0.1-1 247 8 6 1 8 73 3 6 6
 CMOS CMOS Bipolar BiCMOS SOI BCD
 IGBT MEMS GaN SiC
 BCD 1 8 MEMS
 IC 60
 62
 2.4
 2018
 27%

39

			2018
3 6	Analog BCD MEMS DMOS Power Discrete		247
1 8	Analog BCD MEMS DMOS		73
8	MOS MOS MOS SBD		60
			199

MPS International

2018

Diodes Incorporated

Diodes
CIRRUS Logic 1984

BOSE

40	2018		41	2018	
		12,112	4.51%		
		8,940	3.33%		
		8,649	3.22%		
		7,987	2.98%		
		7,638	2.85%		
		45,326	16.89%		

42	
	TCL
	TTi

1.

2016	2017	2018	2019H1	0.14	/
0.13	/	0.15	/	0.16	/
2022		+5%	+10%	+5%	2020-
2020-2022				2020-2022	

			2020-2022						+10%	+20%
+20%					+16%	+32%	+23%			
				ASP					2020-2022	
	-18%	5%	8%							
2020-2022						3%	10%	8%		
			2020-2022							
			MOSFET			24%	26%	26%		
			2020-2022			29%	32%	32%		
					2020-2022				19%	18%
18%										

43

2019

2020E

	2019-2021		58	63	76
IDM	4.0	4.9	6.7		
	2021	90	52.3		
IDM					
		Forward P/E		2020-2023	/
47					

- 1.
- 2.
- 3.
- 4.
- 5.
- 2020 8 27 IPO 5%
- 1191

							1	
0	0	0	0	0	2		3	4
0	0	0	0	0				
0	0	0	0	0				
0	0	0	0	0				
0.00	0.00	0.00	0.00	0.00	1.00 = 3.01~4.0=	1.01~2.0=	2.01~3.0=	

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0755-83830558
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518000

7GH

4001